

MC100EPT23

Dual Differential LVPECL to LVTTTL Translator

The MC100EPT23 is a dual differential LVPECL to LVTTTL translator. Because LVPECL (Positive ECL) levels are used only +3.3V and ground are required. The small outline 8-lead SOIC package and the dual gate design of the EPT23 makes it ideal for applications which require the translation of a clock and a data signal.

The EPT23 is available in only the ECL 100K standard. Since there are no LVPECL outputs or an external V_{BB} reference, the EPT23 does not require both ECL standard versions. The LVPECL inputs are differential. Therefore, the MC100EPT23 can accept any standard differential LVPECL input referenced from a V_{CC} of +3.3V.

- 1.5ns Typical Propagation Delay
- Minimum Operating Frequency > 275MHz
- Differential LVPECL Inputs
- Small Outline SOIC Package
- 24mA LVTTTL Outputs
- Flow Through Pinouts
- Internal Input Resistors: Pulldown on D, Pulldown and Pullup on \bar{D}
- Q Output will default LOW with inputs open or at GND
- ESD Protection: >1.2KV HBM, >150V MM
- Moisture Sensitivity Level 1, Indefinite Time Out of Drypack.
For Additional Information, See Application Note AND8003/D
- Flammability Rating: UL-94 code V-0 @ 1/8",
Oxygen Index 28 to 34
- Transistor Count = 91 devices

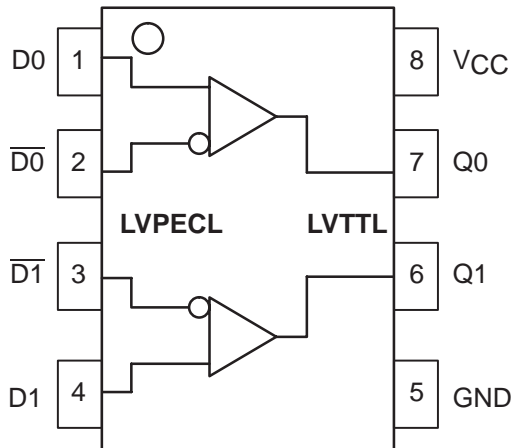
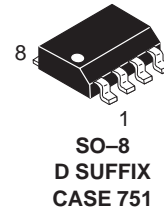


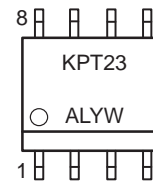
Figure 1. 8-Lead Pinout and Logic Diagram



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MARKING DIAGRAM



A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week

*For additional information, see Application Note AND8002/D

PIN DESCRIPTION	
PIN	FUNCTION
Q0, Q1	LVTTTL Outputs
D0, D1, $\bar{D}0$, $\bar{D}1$	Differential LVPECL Inputs
VCC	Positive Supply
GND	Ground

ORDERING INFORMATION

Device	Package	Shipping
MC100EPT23D	SOIC	98 Units/Rail
MC100EPT23DR2	SOIC	2500 Tape & Reel

MC100EPT23

MAXIMUM RATINGS*

Symbol	Parameter	Value	Unit
V _{CC}	Power Supply (GND = 0V)	0 to 3.8	VDC
V _I	Input Voltage (GND = 0V, V _I not more positive than V _{CC})	0 to 3.8	VDC
I _{out}	Output Current Continuous Surge	50 100	mA
T _A	Operating Temperature Range	-40 to +85	°C
T _{stg}	Storage Temperature	-65 to +150	°C
θ _{JA}	Thermal Resistance (Junction-to-Ambient) Still Air 500lfpm	190 130	°C/W
θ _{JC}	Thermal Resistance (Junction-to-Case)	41 to 44 ± 5%	°C/W
T _{sol}	Solder Temperature (<2 to 3 Seconds: 245°C desired)	265	°C

* Maximum Ratings are those values beyond which damage to the device may occur.

DC CHARACTERISTICS (V_{CC} = 3.3V ± 0.3V; GND = 0V; T_A = -40°C to 85°C)

Symbol	Characteristic	Min	Typ	Max	Unit
I _{CCH}	Power Supply Current (Outputs set to HIGH)	10	18	25	mA
I _{CCL}	Power Supply Current (Outputs set to LOW)	15	26	33	mA
V _{IH}	Input HIGH Voltage (V _{CC} = 3.3) (Note 1.)	2135		2420	mV
V _{IL}	Input LOW Voltage (V _{CC} = 3.3) (Note 1.)	1490		1825	mV
I _{IH}	Input HIGH Current			150	μA
I _{IL}	Input LOW Current	D D̄		0.5	μA
V _{OH}	Output HIGH Voltage (I _{OH} = -3.0mA) (Note 2.)	2.4			V
V _{OL}	Output LOW Voltage (I _{OL} = 24mA) (Note 2.)			0.5	V
I _{OS}	Output Short Circuit Current	-180		-50	mA
V _{IHCMR}	Input HIGH Voltage Common Mode Range (Note 3.)	2.0		3.3	V

NOTE: 100EP circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500lfpm is maintained.

1. All values vary 1:1 with V_{CC}.
2. All loading with 500 ohms to GND, CL = 20pF.
3. V_{IHCMR} min varies 1:1 with GND, max varies 1:1 with V_{CC}.

AC CHARACTERISTICS (V_{CC} = 3.3V ± 0.3V; GND = 0V)

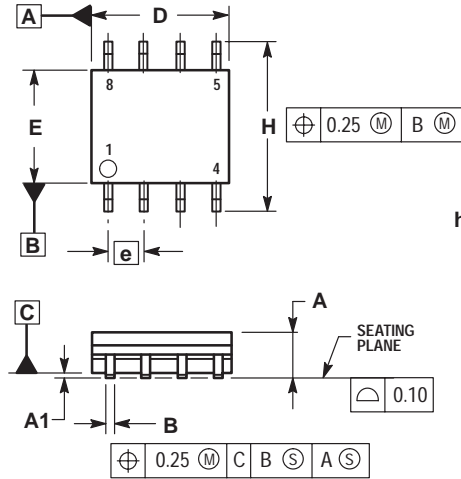
Symbol	Characteristic	-40°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
f _{max}	Maximum Toggle Frequency (Note 4.)	275	350		275	350		275	350		MHz
t _{PLH} , t _{PHL}	Propagation Delay to Output Differential (Note 5.)	1.2	1.5	1.8	1.2	1.5	1.8	1.3	1.7	2.2	ns
t _{SK++} , t _{SK--} , t _{SKPP}	Output-to-Output Skew++ Output-to-Output Skew-- Part-to-Part Skew (Note 6.)		60 25 500			60 25 500			60 25 500		ps
t _{JITTER}	Cycle-to-Cycle Jitter		TBD			TBD			TBD		ps
V _{PP}	Input Voltage Swing (Differential) (Note 7.)	100	800	1200	100	800	1200	100	800	1200	mV
t _r , t _f	Output Rise/Fall Times (20% - 80%) Q, Q̄	330	600	900	330	600	900	330	650	900	ps

4. F_{max} guaranteed for functionality only. V_{OL} and V_{OH} levels are guaranteed at DC only.
5. Reference (V_{CC} = 3.3V ± 5%; GND = 0V)
6. Skews are measured between outputs under identical conditions.
7. 200mV input guarantees full logic swing at the output.

MC100EPT23

PACKAGE DIMENSIONS


SO-8
D SUFFIX
PLASTIC SOIC PACKAGE
CASE 751-06
ISSUE T



NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. DIMENSIONS ARE IN MILLIMETER.
3. DIMENSION D AND E DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 TOTAL IN EXCESS OF THE B DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS	
	MIN	MAX
A	1.35	1.75
A1	0.10	0.25
B	0.35	0.49
C	0.19	0.25
D	4.80	5.00
E	3.80	4.00
e	1.27 BSC	
H	5.80	6.20
h	0.25	0.50
L	0.40	1.25
θ	0°	7°

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